

# XP161A1265PR-G

ETR11023-004

#### **Power MOSFET**

## **■**GENERAL DESCRIPTION

The XP161A1265PR is an N-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics.

Because high-speed switching is possible, the IC can be efficiently set thereby saving energy.

A gate protect diode is built-in to prevent static damage.

The small SOT-89 package makes high density mounting possible.

### **■**APPLICATIONS

- ■Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

#### **■**FEATURES

Low On-State Resistance : Rds(on)=0.055 Ω @ Vgs=4.5V

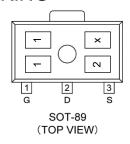
: Rds(on)=0.095  $\Omega$  @ Vgs=2.5V

Ultra High-Speed Switching
Gate Protect Diode Built-in
Driving Voltage : 2.5V
N-Channel Power MOSFET

**DMOS Structure** 

Package : SOT-89

### ■PIN CONFIGURATION/ MARKING



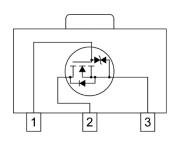
G : Gate
S : Source
D : Drain

#### ■PRODUCT NAME

PRODUCT	PACKAGE	ORDER UNIT
XP161A1265PR-G*	SOT-89	1,000pcs/Reel

(\*) The "-G" suffix denotes Halogen and Antimony free as well as being fully RoHS compliant

## **■**EQUIVALENT CIRCUIT



N-channel MOSFET (1 device built-in)

### ■ ABSOLUTE MAXIMUM RATINGS

Ta = 25°C

PARAMETER	SYMBOL	RATINGS	UNITS
Drain-Source Voltage	Vdss	20	V
Gate-Source Voltage	Vgss	±12	٧
Drain Current (DC)	ld	4	Α
Drain Current (Pulse)	ldp	16	Α
Reverse Drain Current	ldr	4	Α
Channel Power Dissipation *	Pd	2	W
Channel Temperature	Tch	150	လ
Storage Temperature Range	Tstg	-55~150	ပ္

<sup>\*</sup> When implemented on a ceramic PCB (900mm<sup>2</sup> x 0.8mm)

<sup>\*</sup> x represents production lot number.

# **■**ELECTRICAL CHARACTERISTICS

DC Characteristics Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	ldss	Vds=20V, Vgs= 0V	-	-	10	μΑ
Gate-Source Leak Current	lgss	Vgs= ±12V, Vds=0V	-	-	±10	μΑ
Gate-Source Cut-Off Voltage	Vgs(off)	ld= 1mA, Vds= 10V	0.7	-	1.4	V
Drain-Source On-State Resistance*1	Rds(on)	Id= 2A, Vgs= 4.5V	-	0.042	0.055	Ω
		Id= 2A, Vgs= 2.5V	-	0.070	0.095	Ω
Forward Transfer Admittance*1	Yfs	ld= 2A, Vds= 10V	-	8	ı	S
Body Drain Diode Forward Voltage	Vf	If= 4A, Vgs= 0V	-	0.85	1.1	V

<sup>\*1</sup> Effective during pulse test.

## **Dynamic Characteristics**

Ta = 25℃

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	Ciss	Vds= 10V, Vgs=0V f= 1MHz	-	320	-	pF
Output Capacitance	Coss		-	190	-	pF
Feedback Capacitance	Crss		-	80	1	pF

### **Switching Characteristics**

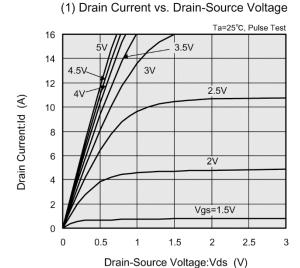
Ta = 25°C

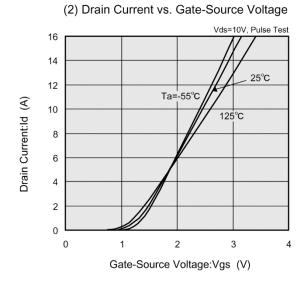
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-On Delay Time	td (on)	Vgs= 5V, Id=2A Vdd= 10V	-	10	-	ns
Rise Time	tr		-	15	-	ns
Turn-Off Delay Time	td (off)		-	55	-	ns
Fall Time	tf		-	40	-	ns

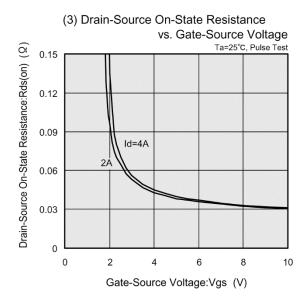
#### Thermal Characteristics

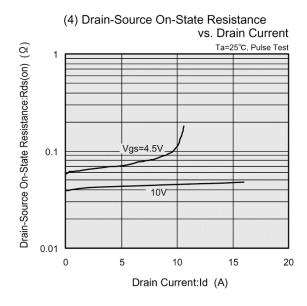
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (Channel-Ambience)	Rth (ch-a)	Implement on a ceramic PCB	-	62.5	-	°C/W

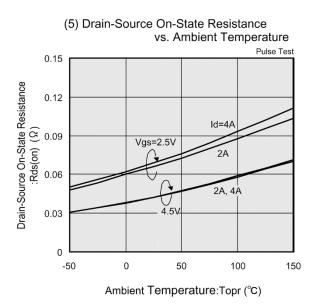
## **■**TYPICAL PERFORMANCE CHARACTERISTICS

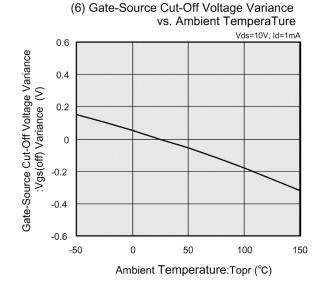




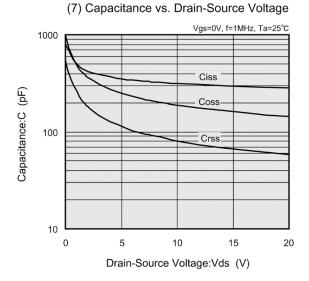


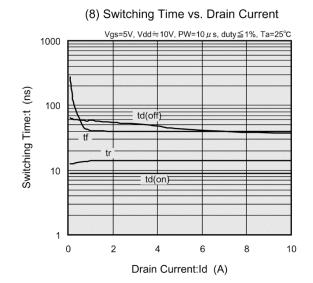


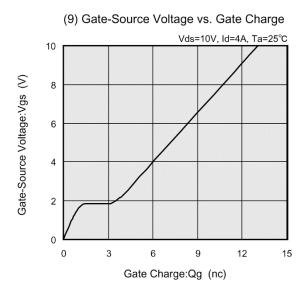


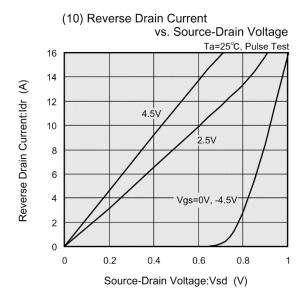


# ■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

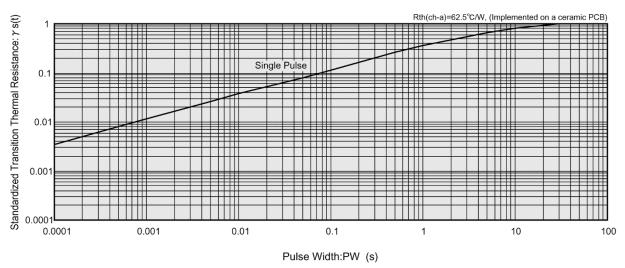








(11) Standardized transition Thermal Resistance vs. Pulse Width



# **■**PACKAGING INFORMATION

For the latest package information go to, <a href="https://www.torexsemi.com/technical-support/packages">www.torexsemi.com/technical-support/packages</a>

PACKAGE	OUTLINE / LAND PATTERN	THERMAL CHARACTERISTICS
SOT-89	SOT-89 PKG	SOT-89 Power Dissipation

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